Vishay Telefunken

Silicon NPN Planar RF Transistor

Electrostatic sensitive device.

Observe precautions for handling.

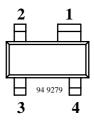


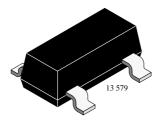
Applications

For low noise applications such as preamplifiers, mixers and oscillators in analog and digital TV–systems (e.g., satellite tuners) up to microwave frequencies.

Features

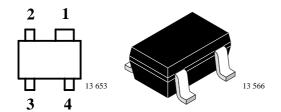
- Low power applications
- Very low noise figure
- High transition frequency f_T = 12 GHz





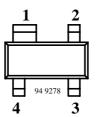
TSDF1220 Marking: F20 Plastic case (SOT 143)

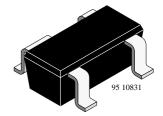
1 = Collector, 2 = Emitter, 3 = Base, 4 = Emitter



TSDF1220W Marking: WF2 Plastic case (SOT 343)

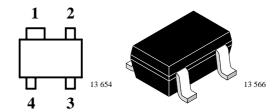
1 = Collector, 2 = Emitter, 3 = Base, 4 = Emitter





TSDF1220R Marking: 20F Plastic case (SOT 143R)

1 = Collector, 2 = Emitter, 3 = Base, 4 = Emitter



TSDF1220RW Marking: W2F Plastic case (SOT 343R)

1 = Collector, 2 = Emitter, 3 = Base, 4 = Emitter

Absolute Maximum Ratings

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Collector-base voltage		V_{CBO}	9	V
Collector-emitter voltage		V_{CEO}	6	>
Emitter-base voltage		V_{EBO}	2	V
Collector current		Ic	40	mA
Total power dissipation	T _{amb} ≤ 60 °C	P_{tot}	200	mW
Junction temperature		Τį	150	°C
Storage temperature range		T _{stg}	-65 to +150	°C





Maximum Thermal Resistance

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test Conditions	Symbol	Value	Unit
Junction ambient	on glass fibre printed board (25 x 20 x 1.5) mm ³	R _{thJA}	450	K/W
	plated with 35µm Cu			

Electrical DC Characteristics

T_{amb} = 25°C, unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Collector cut-off current	$V_{CE} = 12 \text{ V}, V_{BE} = 0$	I _{CES}			100	μА
Collector-base cut-off current	$V_{CB} = 10 \text{ V}, I_{E} = 0$	I _{CBO}			100	nA
Emitter-base cut-off current	$V_{EB} = 1 \text{ V, } I_{C} = 0$	I _{EBO}			2	μΑ
Collector-emitter breakdown voltage	$I_C = 1 \text{ mA}, I_B = 0$	V _{(BR)CEO}	6			/
Collector-emitter saturation voltage	$I_C = 30 \text{ mA}, I_B = 3 \text{ mA}$	V _{CEsat}		0.1	0.5	/
DC forward current transfer ratio	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}$	h _{FE}	50	100	150	

Electrical AC Characteristics

 $T_{amb} = 25$ °C, unless otherwise specified

Parameter	Test Conditions	Symbol	Min	Тур	Max	Unit
Transition frequency	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}, f = 1 \text{ GHz}$	f _T		12		GHz
Collector-base capacitance	V _{CB} = 1 V, f = 1 MHz	C _{cb}		0.3		рF
Collector-emitter capacitance	V _{CE} = 1 V, f = 1 MHz	C _{ce}		0.35		рF
Emitter-base capacitance	$V_{EB} = 0.5 \text{ V, f} = 1 \text{ MHz}$	C _{eb}		0.5		pF
Noise figure	$V_{CE} = 5 \text{ V}, I_{C} = 3 \text{ mA},$	F		1.2		dB
	$Z_S = Z_{Sopt}$, $Z_L = 50 \Omega$, $f = 2 GHz$					
Power gain	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA},$	Gpe		14		dB
	$Z_S = Z_{Sopt}$, $Z_L = 50 \Omega$, $f = 2 GHz$	<u> </u>				
Transducer gain	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA},$	$ S_{21e} ^2$		12.5		dB
	$Z_0 = 50 \Omega$, $f = 2 GHz$					
Third order intercept point at	$V_{CE} = 5 \text{ V}, I_{C} = 20 \text{ mA}, f = 2 \text{ GHz}$	IP ₃		22		dBm
output						



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Typical Characteristics $(T_{amb} = 25^{\circ}C \text{ unless otherwise specified})$

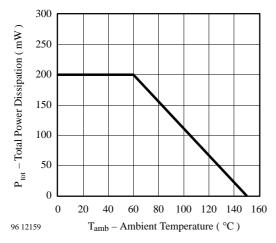


Figure 1. Total Power Dissipation vs. Ambient Temperature

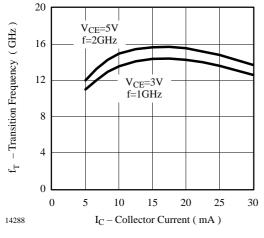


Figure 2. Transition Frequency vs. Collector Current

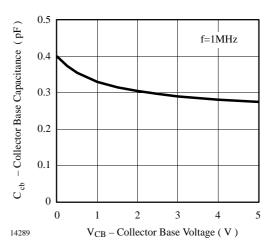


Figure 3. Collector Base Capacitance vs. Collector Base Voltage

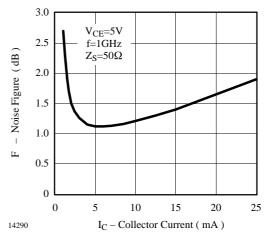
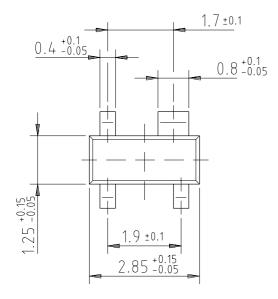


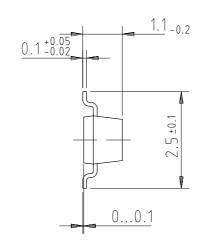
Figure 4. Noise Figure vs. Collector Current

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Dimensions of TSDF1220 in mm

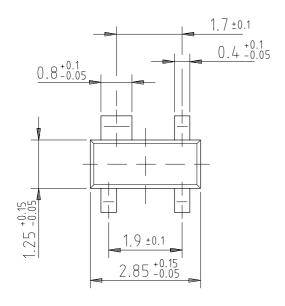


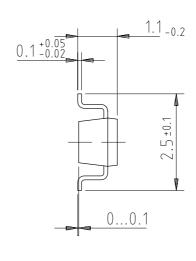


96 12240



Dimensions of TSDF1220R in mm





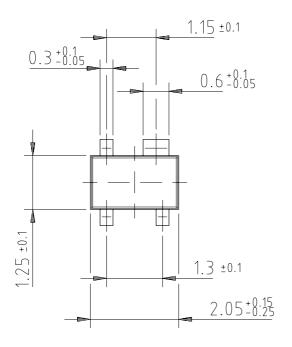
96 12239

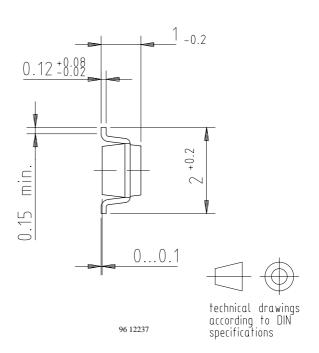
technical drawings according to DIN specifications



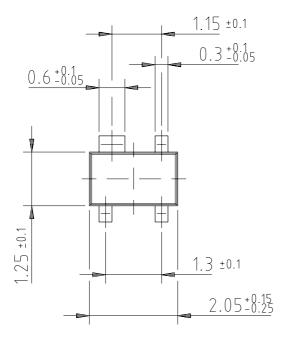
Vishay Telefunken

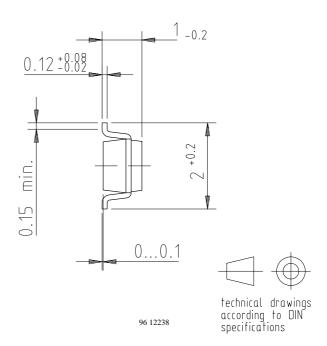
Dimensions of TSDF1220W in mm





Dimensions of TSDF1220RW in mm





Vishay Telefunken



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice. Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay-Telefunken products for any unintended or unauthorized application, the buyer shall indemnify Vishay-Telefunken against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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